

PI6C4921506

High Performance LVDS Fanout Buffer

Features

- 6 LVDS outputs
- Up to 1.5GHz output frequency
- Ultra low additive phase jitter: < 0.03 ps (typ) (differential 156.25MHz, 12KHz to 20MHz integration range)
- Single differential input
- Low delay from input to output (Tpd typ. < 1.5ns)
- Separate Input output supply voltage for level shifting
- 2.5V / 3.3V power supply
- Industrial temperature support
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. “Green” Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/product-definitions/) or your local Diodes representative.
- Packaging (Pb-free & Green):
 - 24-Pin, (TSSOP)

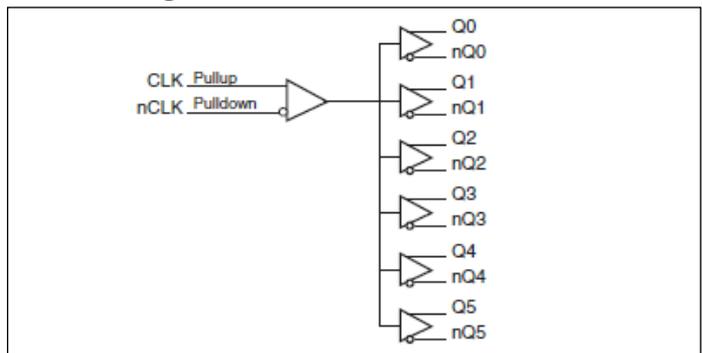
Description

The PI6C4921506 is a high performance fanout buffer device which supports up to 1.5GHz frequency. The device also uses Diodes' proprietary input detection technique to make sure illegal input conditions will be detected and reflected by output states. This device is ideal for systems that need to distribute low jitter clock signals to multiple destinations.

Applications

- Networking systems including switches and Routers
- High frequency backplane based computing and telecom platforms

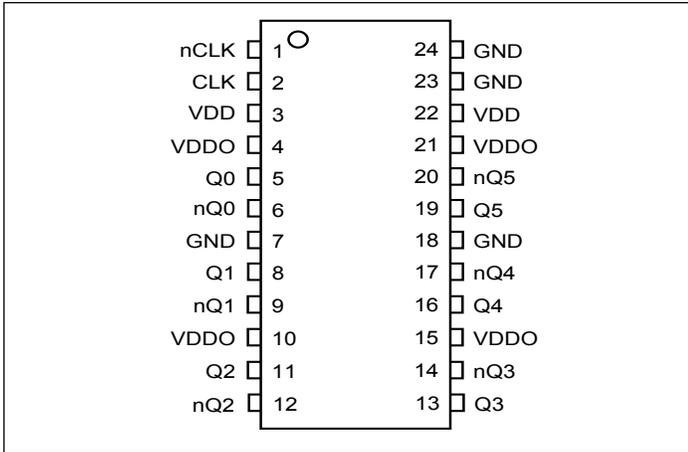
Block Diagram



Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Configuration



Pin Description

Pin #	Pin Name	Type	Description
1, 2	nCLK	Input	Differential clock input
	CLK		
3, 22	V _{DD}	Power	Power supply
4, 10, 15, 21	V _{DDO}	Power	IO power supply
5, 6	Q0	Output	LVDS output clock
	nQ0		
7, 18, 23, 24	GND	Power	Ground
8, 9	Q1	Output	LVDS output clock
	nQ1		
11, 12	Q2	Output	LVDS output clock
	nQ2		
13, 14	Q3	Output	LVDS output clock
	nQ3		
16, 17	Q4	Output	LVDS output clock
	nQ4		
19, 20	Q5	Output	LVDS output clock
	nQ5		

Clock Input Function Table

Inputs		Outputs		Input to Output Mode	Polarity
CLK	nCLK	Q0:Q5	nQ0:nQ5		
0	1	LOW	HIGH	Differential to Differential	Non Inverting
1	0	HIGH	LOW	Differential to Differential	Non Inverting
0	Biased	LOW	HIGH	Single Ended to Differential	Non Inverting
1	Biased	HIGH	LOW	Single Ended to Differential	Non Inverting
Biased	0	HIGH	LOW	Single Ended to Differential	Inverting
Biased	1	LOW	HIGH	Single Ended to Differential	Inverting

Maximum Ratings (Above which the useful life may be impaired. For user guidelines, not tested)

Supply Voltage, V_{DD}	4.65V
Inputs, V_I	0.5V to $V_{DD}+0.5V$
Outputs, I_O (LVDS)	
Continuous Current	10mA
Surge Current	15mA
Package Thermal Impedance, Θ_{JA}	70°C/W (0 mps)
Storage temperature, T_{STG} (Junction-to-Ambient).....	-65 to +150°C

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Power Supply DC Characteristics ($V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{DD}	Positive Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				70	mA
I_{DDO}	Output Supply Current				100	mA

Power Supply DC Characteristics ($V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				65	mA
I_{DDO}	Output Supply Current				102	mA

Differential DC Characteristics ($V_{DD} = V_{DDO} = 3.3V \pm 5\%$ or $2.5V \pm 5\%$, $T_A = -40^\circ C$ to $85^\circ C$)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
I_{IH}	Input High Current	CLK	$V_{IN} = V_{DD}$		10	μA
		nCLK	$V_{IN} = V_{DD}$		150	μA
I_{IL}	Input Low Current	CLK	$V_{IN} = 0V$	-150		μA
		nCLK	$V_{IN} = 0V$	-10		μA
V_{PP}	Peak-to-Peak Input Voltage ⁽¹⁾		0.15		1.3	V
V_{CMR}	Common Mode Input Voltage ^(1,2)		GND+0.5		$V_{DD}-0.85$	V

Note:

1. V_{IL} should not be less than -0.3V
2. Common mode voltage is defined as V_H

LVDS DC Characteristics ($V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{OD}	Differential Output Voltage		326		526	mV
ΔV_{OD}	V_{OD} Magnitude Change				50	mV
V_{OS}	Offset Voltage		1.2		1.3	V
ΔV_{OS}	V_{OS} Magnitude Change				50	mV

Note:
 Please refer to Parameter Measurement Information for output information.

LVDS DC Characteristics ($V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V_{OD}	Differential Output Voltage		305		505	mV
ΔV_{OD}	V_{OD} Magnitude Change				50	mV
V_{OS}	Offset Voltage		1.15		1.3	V
ΔV_{OS}	V_{OS} Magnitude Change				50	mV

Note:
 Please refer to Parameter Measurement Information for output information.

AC Characteristics ($V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
f_{MAX}	Output Frequency				1.5	GHz
t_{PD}	Propagation Delay ⁽¹⁾		800		1100	ps
$t_{sk(o)}$	Output Skew ^(2, 3)				55	ps
t_{jit}	Buffer Additive Phase Jitter, RMS	622.08MHz, Integration Range: 12kHz – 20MHz		0.067		ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	50		250	ps
odc	Output Duty Cycle	$\leq 622\text{MHz}$	47		53	%

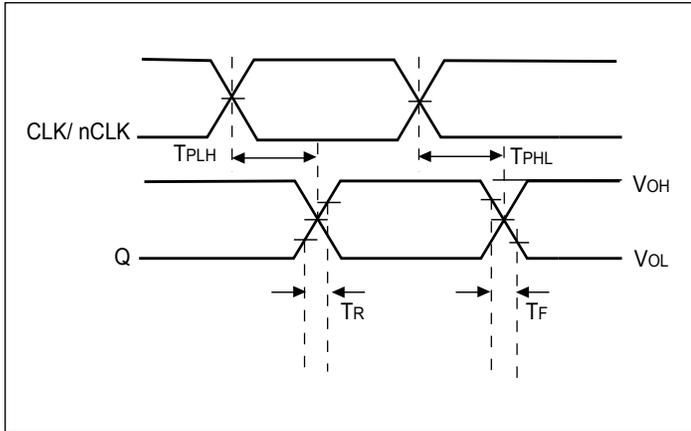
Note:
 Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

1. Measured from the differential input crossing point to the differential output crossing point.
2. Defined as skew between outputs at the same supply voltage and with equal load conditions. Measured from at the output differential cross points.
3. This parameter is defined in accordance with JEDEC Standard 65.

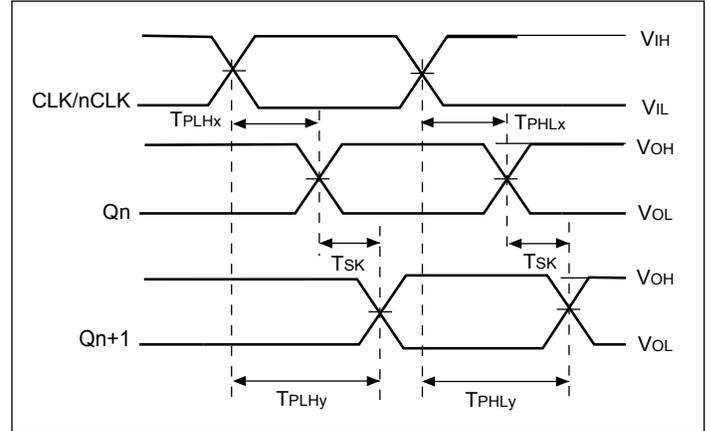
AC Characteristics ($V_{DD} = V_{DDO} = 2.5V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
f_{MAX}	Output Frequency				1.5	GHz
t_{PD}	Propagation Delay ⁽¹⁾		800		1200	ps
$t_{sk(o)}$	Output Skew ^(2, 3)				55	ps
t_{jit}	Buffer Additive Phase Jitter, RMS	622.08MHz, Integration Range: 12kHz – 20MHz		0.067		ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	50		250	ps
odc	Output Duty Cycle	$\leq 622\text{MHz}$	47		53	%

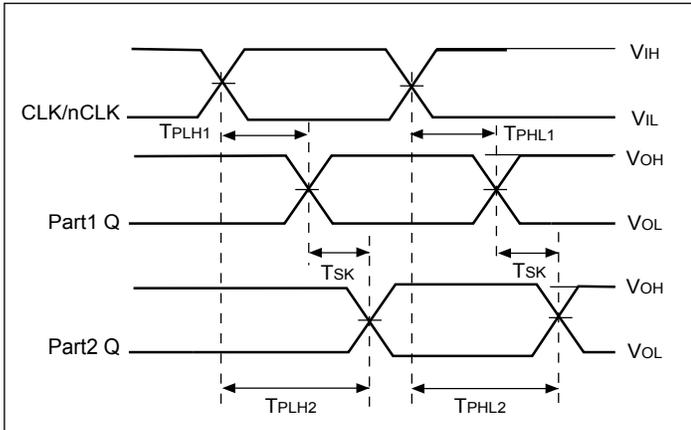
Propagation Delay T_{PD}



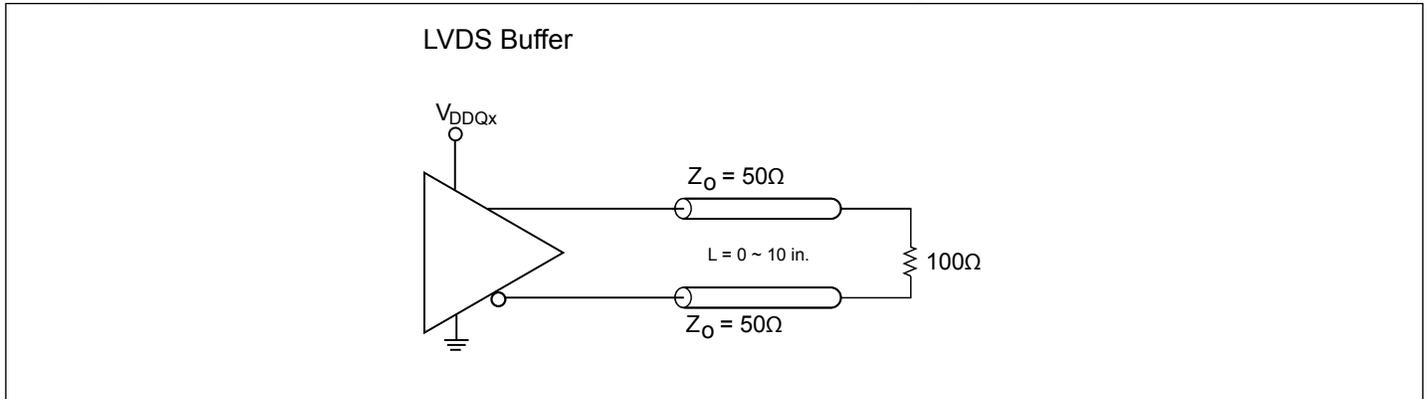
Output Skew



Part to Part Skew

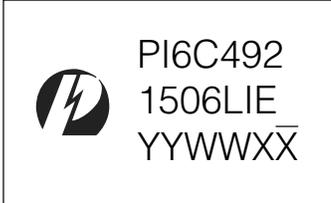


Configuration Test Load Board Termination for LVDS Outputs



PI6C4921506

Part Marking



YY: Year

WW: Workweek

1st X: Assembly Code

2nd X: Fab Code

Packaging Mechanical: 24-TSSOP (L)

SYMBOLS	MIN.	NOM.	MAX.
A	—	—	1.20
A1	0.05	—	0.15
A2	0.80	1.00	1.05
b	0.19	—	0.30
c	0.09	—	0.20
D	7.70	7.80	7.90
E1	4.30	4.40	4.50
E	6.20	6.40	6.60
[e]	0.65 BSC		
L1	1.00 REF		
L	0.45	0.60	0.75
S	0.20	—	—
θ	0°	—	8°

NOTES:
 1. ALL DIMENSIONS IN MILLIMETERS. ANGLES IN DEGREES.
 2. JEDEC MO-153F
 3. DIMENSIONS DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.

PERICOM
Enabling Serial Connectivity

DATE: 03/31/16

DESCRIPTION: 24-Pin, 173mil Wide TSSOP

PACKAGE CODE: L (L24)

DOCUMENT CONTROL #: PD-1312

REVISION: G

16-0075

For latest package info.

please check: <http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/>

Ordering Information

Ordering Number	Package Code	Package Description
PI6C4921506LIEX	L	24-Pin, 173mil Wide (TSSOP)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. I = Industrial
5. E = Pb-free and Green
6. X suffix = Tape/Reel

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